

VOLTAGE RANGE: 200- 1000V

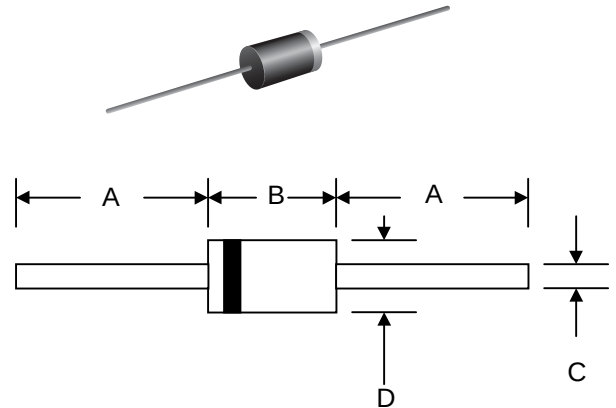
CURRENT: 1.0 A

Features

- Low cost
- Diffused junction
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents

Mechanical Data

- Case: D O - 4 1 Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-41		
Dim	Min	Max
A	25.4	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

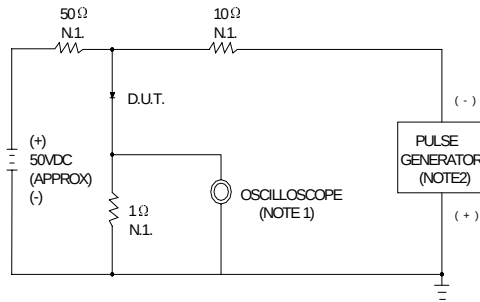
Characteristic	Symbol	1N4942G	1N4944G	1N4946G	1N4947G	1N4948G	Unit
Maximum recurrent peak reverse voltage	V_{RRM}	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	200	400	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A = 75^\circ\text{C}$	$I_{F(AV)}$	1.0					A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J = 125^\circ\text{C}$	I_{FSM}	30.0					A
Maximum instantaneous forward voltage @ 1.0 A	V_F	1.3					V
Maximum reverse current @ $T_A = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_A = 100^\circ\text{C}$	I_R	5.0 100					μA
Maximum reverse recovery time (Note1)	t_{rr}	150		250		500	ns
Typical junction capacitance (Note2)	C_J	12					pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	55					$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55---- +150					$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55---- + 150					$^\circ\text{C}$

NOTE: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $I_{rr} = 0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22PF
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

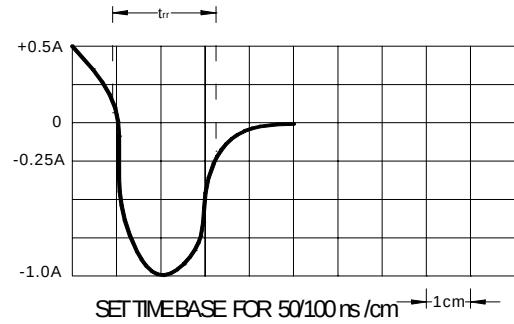
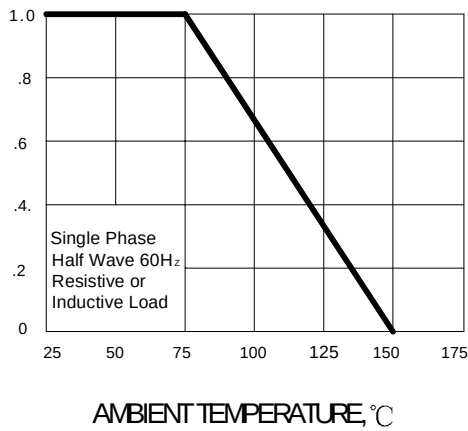


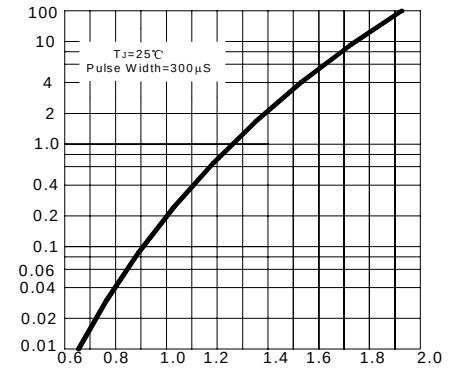
FIG.2 – FORWARD DERATING CURVE

AVERAGE FORWARD CURRENT
AMPERES



INSTANTANEOUS FORWARD CURRENT
AMPERES

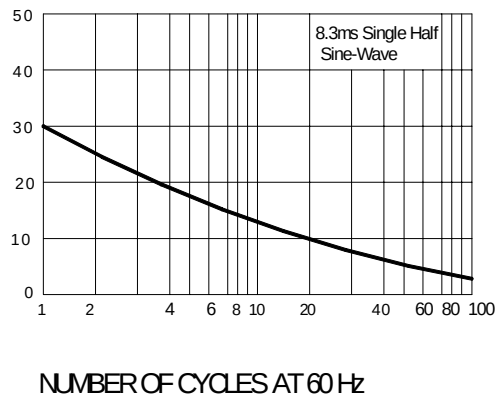
FIG.3 – TYPICAL FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4-PEAK FORWARD SURGE CURRENT

PEAK FORWARD SURGE CURRENT
AMPERES



JUNCTION CAPACITANCE,pF

FIG.5- TYPICAL JUNCTION CAPACITANCE

